Comment on "Unraveling the 'Pressure Effect' in Nucleation"

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In a 2008 Letter, Wedekind *et al.* [\[1](#page-0-1)] discussed the influence of an inert carrier gas on the vapor–liquid nucleation rate. They found an additional "pressure–volume work" that is performed against the carrier gas, and also quantified the nonisothermal effects arising from the carrier gas. We will argue that the pressure–volume work term represents the influence of the carrier gas on phase equilibrium itself. This term will not appear explicitly when a definition of the supersaturation is used that is appropriate for high-pressure nucleation.

The presence of a background gas causes an increase in the equilibrium vapor pressure (even when all substances are ideal), which is known as the Poynting effect [\[2](#page-0-2)]. Consider a vapor in equilibrium with its liquid phase in the presence of a carrier gas. We will use the same notation as Wedekind *et al.*, that is, p is the vapor pressure, p_{eq} is the equilibrium vapor pressure, and p_c is the carrier gas pressure. In addition, we denote the total pressure as $p_t = p + p_c$. From an integration of the Gibbs–Duhem equation $d\mu = v dp$ it follows that the chemical potential of the liquid μ_{ℓ} at pressure p_t is

$$
\mu_{\ell}(p_{t}) = \mu_{\ell}^{0}(p_{eq}^{0}) + \nu_{\ell}(p_{t} - p_{eq}^{0}), \qquad (1)
$$

where superscript 0 denotes pure-component properties, and v_{ℓ} is the molecular volume. Similarly, the chemical potential of the ideal vapor μ _v at partial pressure p_{eq} and total pressure *p*t is

$$
\mu_{\rm v}(p_{\rm eq}, p_{\rm t}) = \mu_{\rm v}^0(p_{\rm eq}^0) + k_{\rm B}T \ln(p_{\rm eq}/p_{\rm eq}^0),\tag{2}
$$

where k_B is the Boltzmann constant and T the temperature. Conditions of phase equilibria for a pure vapor and for a vapor with carrier gas require

$$
\mu_{\ell}^{0}(p_{\text{eq}}^{0}) = \mu_{\text{v}}^{0}(p_{\text{eq}}^{0})
$$
 and $\mu_{\ell}(p_{\text{t}}) = \mu_{\text{v}}(p_{\text{eq}}, p_{\text{t}})$, (3)

which yields for the equilibrium vapor pressure p_{eq} in the presence of a carrier gas and total pressure p_t

$$
p_{\text{eq}} = p_{\text{eq}}^0 \exp\left[\frac{v_\ell (p_t - p_{\text{eq}}^0)}{k_{\text{B}} T}\right],\tag{4}
$$

where the exponential is known as the Poynting factor.

The work of formation of a droplet of *n* molecules is

$$
\Delta G = n \big[\mu_\ell(p_\ell) - \mu_\nu(p, p_t) \big] - n \nu_\ell(p_\ell - p_t) + \gamma A, \quad (5)
$$

where p_{ℓ} is the pressure in the droplet, γ is the surface tension, and $A = s_1 n^{2/3}$ is the area of the droplet with s_1 the surface area per monomer. Analogously to Eqs. [\(1\)](#page-0-3) and [\(2\)](#page-0-4) we obtain

$$
\mu_{\ell}(p_{\ell}) = \mu_{\ell}^{0}(p_{\text{eq}}^{0}) + v_{\ell}(p_{\ell} - p_{\text{eq}}^{0})
$$
 (6)

$$
\mu_{\rm v}(p, p_{\rm t}) = \mu_{\rm v}^0(p_{\rm eq}^0) + k_{\rm B} T \ln(p/p_{\rm eq}^0),\tag{7}
$$

and therefore

$$
\Delta G = n \left[v_{\ell} (p_{\rm t} - p_{\rm eq}^0) - k_{\rm B} T \ln(p/p_{\rm eq}^0) \right] + \gamma A, \tag{8}
$$

which corresponds to Eq. (5) of Wedekind *et al.*, with their definition of the supersaturation, denoted here as $S_{\rm W} = p/p_{\rm eq}^0$. The term $n v_\ell (p_t - p_{\text{eq}}^0)$ includes the additional pressure– volume work against the carrier gas $W_c = nv_{\ell}p_c$ that was introduced by Wedekind *et al.*

To incorporate carrier gas effects, the appropriate definition of supersaturation should be based on the difference of the chemical potential of the vapor in the actual state and at phase equilibrium at the actual total pressure as [\[3](#page-0-5)[–7\]](#page-1-0)

$$
S = \exp\left[\frac{\mu_{\rm v}(p, p_{\rm t}) - \mu_{\rm v}(p_{\rm eq}, p_{\rm t})}{k_{\rm B}T}\right].
$$
 (9)

With this definition, the work of formation becomes

$$
\Delta G = -n k_{\rm B} T \ln S + \gamma A, \qquad (10)
$$

and no pressure–volume term appears. Equation [\(10\)](#page-0-6) was derived without assuming ideal gas behavior and is therefore also valid for real gases and vapors. For ideal gases, definition [\(9\)](#page-0-7) becomes

$$
S = \frac{p}{p_{\text{eq}}} = \frac{p}{p_{\text{eq}}^0} \exp\left[-\frac{v_\ell(p_{\text{t}} - p_{\text{eq}}^0)}{k_{\text{B}}T}\right].\tag{11}
$$

This definition of *S* differs from *S_W* by the Poynting factor. When comparing our Eq. [\(10\)](#page-0-6) with Eqs. (5) and (6) in Ref. [1,](#page-0-1) it can be seen that the pressure–volume term occurs when the Poynting effect is not included in the definition of the supersaturation. It should be noted that $S = 1$ refers to phase equilibrium at a given p_c and *T*, while $S_W = 1$ does not. As a consequence, the nucleation rate *J* vanishes for $S \rightarrow 1$, but not for $S_W \rightarrow 1$ $S_W \rightarrow 1$. In fact, the nucleation rate expression in Ref. 1 $J_{pV}(S_{\rm W}, p_{\rm c}, T)$ requires a lower limit of validity $S_{\rm W}^{\rm min}(p_{\rm c}, T)$, while the lower bound for $J(S,T)$ equals $S = 1$ with our definition of the supersaturation.

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